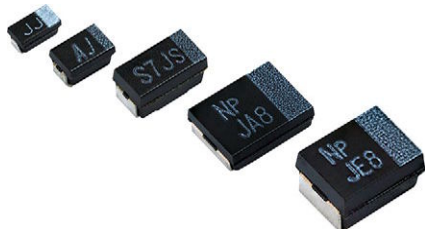


vPolyTan™ Polymer Surface Mount Chip Capacitors, Molded Case, Hi-Rel COTS



RoHS
COMPLIANT
HALOGEN
FREE
GREEN
(5-2008)

FEATURES

- Ultra low ESR
- High reliability processing including:
 - 100 % surge current tested
 - Accelerated voltage conditioning
 - Thermal shock
 - Statistical DC leakage screening at elevated temperature and voltage, covered by U.S. patent and worldwide patents pending.
- PATENT(S): www.vishay.com/patents/
- High ripple current capability
- Stable capacitance over operating temperature, voltage, and frequency range
- No wear out effect
- Terminations: Ni / Pd / Au
- Compatible with “high volume” automatic pick and place equipment
- Moisture sensitivity level 3
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

LINKS TO ADDITIONAL RESOURCES



PERFORMANCE / ELECTRICAL CHARACTERISTICS

Operating Temperature: -55 °C to +105 °C / 125 °C

Capacitance Range: 10 µF to 470 µF

Capacitance Tolerance: ± 20 %

Voltage Rating: 2.5 V_{DC} to 50 V_{DC}

APPLICATIONS

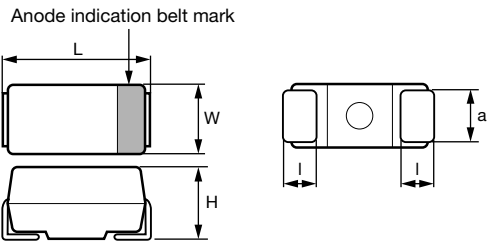
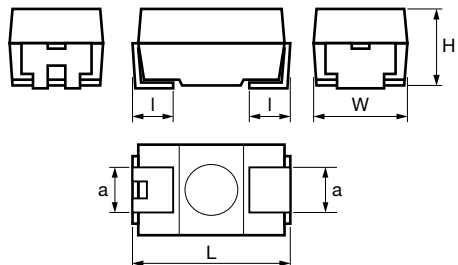
- Decoupling, smoothing, filtering
- Switch mode and point of load power supply
- Infrastructure equipment
- Storage and networking

ORDERING INFORMATION								
T56	D	107	M	010	C	S	A	025
TYPE	CASE CODE	CAPACITANCE	CAPACITANCE TOLERANCE	DC VOLTAGE RATING	TERMINATION / PACKAGING	RELIABILITY LEVEL	SURGE CURRENT LEVEL	ESR
	See Ratings and Case Codes table.	This is expressed in picofarads. The first two digits are the significant figures. The third is the number of zeros to follow.	M = ± 20 %	2R5 = 2.5 V 004 = 4 V 6R3 = 6.3 V 010 = 10 V 12R = 12.5 V 016 = 16 V 020 = 20 V 025 = 25 V 035 = 35 V 050 = 50 V	C = lead (Pb)-free solderable coating, 7" reel	S = hi-rel standard (40 h burn-in) Z = non-ER	A = 10 cycles at +25 °C B = 10 cycles at -55 °C / +85 °C S = 3 cycles at +25 °C	Maximum 100 kHz ESR in mΩ

PATENT(S): www.vishay.com/patents

This Vishay product is protected by one or more United States and international patents.

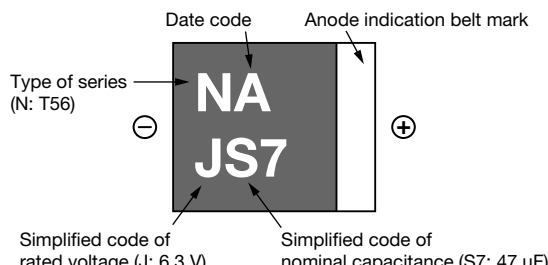
DIMENSIONS in inches [millimeters]

B case				D, V case		
 Anode indication belt mark L W H a				 H L a		
CASE CODE	EIA SIZE	L	W	H	I	a
B	3528-21	0.138 ± 0.008 [3.5 ± 0.2]	0.110 ± 0.008 [2.8 ± 0.2]	0.075 ± 0.008 [1.9 ± 0.2]	0.030 ± 0.012 [0.8 ± 0.3]	0.087 ± 0.008 [2.2 ± 0.2]
V	7343-20	0.287 ± 0.008 [7.3 ± 0.2]	0.169 ± 0.012 [4.3 ± 0.3]	0.075 ± 0.004 [1.9 ± 0.1]	0.051 ± 0.012 [1.3 ± 0.3]	0.094 ± 0.008 [2.4 ± 0.2]
D	7343-31	0.287 ± 0.008 [7.3 ± 0.2]	0.169 ± 0.012 [4.3 ± 0.3]	0.110 ± 0.012 [2.8 ± 0.3]	0.051 ± 0.012 [1.3 ± 0.3]	0.094 ± 0.008 [2.4 ± 0.2]

RATINGS AND CASE CODES

μF	2.5 V	4.0 V	6.3 V	10 V	16 V	20 V	25 V	35 V	50 V
10								D/B	D
15						B/V	B/V	V	
22					B	V	V	D	
33			B	B	D/V	V	D/V		
47	B	B	B	B	D/V				
68	B	B		V	V				
100			V	D/V	D/V		D		
150		V	D/V	D/V					
220	V	D/V	D/V	D/V					
330	V	D/V	D/V	D					
470	V								

MARKING

	
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VOLTAGE CODE		CAPACITANCE CODE	
V	CODE	CAP, μF	CODE
2.5	e	10	A7
4	G	15	E7
6.3	J	22	J7
10	A	33	N7
16	C	47	S7
20	D	68	W7
25	E	100	A8
35	V	150	E8
50	H	220	J8
		330	N8
		470	S8



DATE CODE												
YEAR	MONTH											
	1	2	3	4	5	6	7	8	9	10	11	12
2017	A	B	C	D	E	F	G	H	J	K	L	M
2018	N	P	Q	R	S	T	U	V	W	X	Y	Z
2019	a	b	c	d	e	f	g	h	j	k	l	m
2020	n	p	q	r	s	t	u	v	w	x	y	z
2021	A	B	C	D	E	F	G	H	J	K	L	M
2022	N	P	Q	R	S	T	U	V	W	X	Y	Z
2023	a	b	c	d	e	f	g	h	j	k	l	m
2024	n	p	q	r	s	t	u	v	w	x	y	z

Note

- Marking code repeats every four years in alphabetical order (letter of I, i, O, and o are excluded)

STANDARD RATINGS									
CAPACITANCE (μF)	CASE CODE	PART NUMBER	MAX. DCL AT 25 °C (μA)	MAX. DF AT 25 °C 120 Hz (%)	MAX. ESR AT + 25 °C 100 kHz (mΩ)	MAX. RIPPLE AT 45 °C 100 kHz I _{RMS} (A)	MAX. OPERATING TEMPERATURE (°C)	85 °C / 85 % R. V., 500 h CAPABLE	
2.5 V _{DC} AT +105 °C; 1.7 V _{DC} AT +125 °C									
47	B	T56B476M2R5C(1)(2)070	11.7	8	70	1.36	105		
68	B	T56B686M2R5C(1)(2)070	17.0	8	70	1.36	105		
220	V	T56V227M2R5C(1)(2)025	55.0	10	25	2.73	105		
330	V	T56V337M2R5C(1)(2)025	82.5	10	25	2.73	105		
470	V	T56V477M2R5C(1)(2)025	117.5	10	25	2.73	105		
4 V _{DC} AT +105 °C; 2.7 V _{DC} AT +125 °C									
47	B	T56B476M004C(1)(2)070	18.8	8	70	1.36	105		
68	B	T56B686M004C(1)(2)070	27.2	8	70	1.36	105		
150	V	T56V157M004C(1)(2)025	60.0	10	25	2.73	105		
220	D	T56D227M004C(1)(2)025	88.0	10	25	3.00	125		•
220	V	T56V227M004C(1)(2)025	88.0	10	25	2.73	105		
330	D	T56D337M004C(1)(2)025	132.0	10	25	3.00	125		•
330	V	T56V337M004C(1)(2)025	132.0	10	25	2.73	105		
6.3 V _{DC} AT +105 °C; 4.2 V _{DC} AT +125 °C									
33	B	T56B336M6R3C(1)(2)070	20.7	8	70	1.36	105		
47	B	T56B476M6R3C(1)(2)070	29.6	8	70	1.36	105		
100	V	T56V107M6R3C(1)(2)045	63.0	10	45	2.03	105		
150	D	T56D157M6R3C(1)(2)025	94.5	10	25	3.00	125		•
150	V	T56V157M6R3C(1)(2)025	94.5	10	25	2.73	105		
220	D	T56D227M6R3C(1)(2)025	138.6	10	25	3.00	125		•
220	V	T56V227M6R3C(1)(2)025	138.6	10	25	2.73	105		
330	D	T56D337M6R3C(1)(2)025	207.9	10	25	3.00	125		•
330	V	T56V337M6R3C(1)(2)025	207.9	10	25	2.73	105		

Note

- Part number definitions:
 - (1) Reliability level: Z, S
 - (2) Surge current: A, B, S



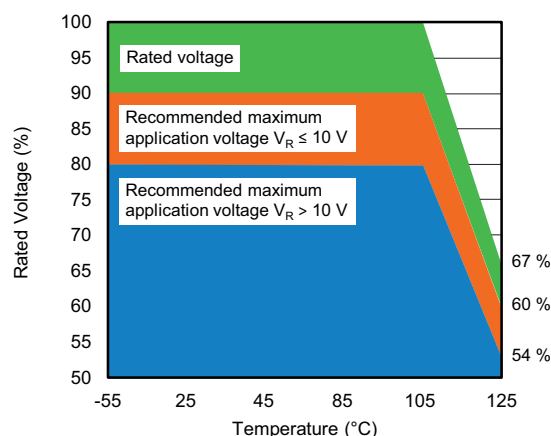
STANDARD RATINGS								
CAPACITANCE (μ F)	CASE CODE	PART NUMBER	MAX. DCL AT 25 °C (μ A)	MAX. DF AT 25 °C 120 Hz (%)	MAX. ESR AT + 25 °C 100 kHz (m Ω)	MAX. RIPPLE AT 45 °C 100 kHz I _{RMS} (A)	MAX. OPERATING TEMPERATURE (°C)	85 °C / 85 %, R. V., 500 h CAPABLE
10 V _{DC} AT +105 °C; 6.7 V _{DC} AT +125 °C								
33	B	T56B336M010C(1)(2)070	33.0	8	70	1.36	105	
47	B	T56B476M010C(1)(2)070	47.0	8	70	1.36	105	
68	V	T56V686M010C(1)(2)060	68.0	10	60	1.76	105	
100	D	T56D107M010C(1)(2)025	100.0	10	25	3.00	105	
100	D	T56D107M010C(1)(2)040	100.0	10	40	2.37	125	•
100	V	T56V107M010C(1)(2)045	100.0	10	45	2.03	105	
150	D	T56D157M010C(1)(2)025	150.0	10	25	3.00	105	
150	V	T56V157M010C(1)(2)025	150.0	10	25	2.73	105	
220	D	T56D227M010C(1)(2)025	220.0	10	25	3.00	105	
220	D	T56D227M010C(1)(2)040	220.0	10	40	2.37	125	•
220	V	T56V227M010C(1)(2)025	220.0	10	25	2.73	105	
330	D	T56D337M010C(1)(2)025	330.0	10	25	3.00	105	
16 V _{DC} AT +105 °C; 10.7 V _{DC} AT +125 °C								
22	B	T56B226M016C(1)(2)070	35.2	8	70	1.36	105	
33	D	T56D336M016C(1)(2)070	52.8	10	70	1.79	125	•
33	V	T56V336M016C(1)(2)070	52.8	10	70	1.63	105	
47	D	T56D476M016C(1)(2)070	75.2	10	70	1.79	125	•
47	V	T56V476M016C(1)(2)070	75.2	10	70	1.63	105	
68	V	T56V686M016C(1)(2)070	108.8	10	70	1.63	105	
100	D	T56D107M016C(1)(2)050	160.0	10	50	2.12	125	•
100	V	T56V107M016C(1)(2)050	160.0	10	50	1.93	105	
20 V _{DC} AT +105 °C; 13.4 V _{DC} AT +125 °C								
15	B	T56B156M020C(1)(2)090	30.0	8	90	1.2	105	
15	V	T56V156M020C(1)(2)125	30.0	10	125	1.22	105	
22	V	T56V226M020C(1)(2)040	44.0	10	40	2.16	105	
33	V	T56V336M020C(1)(2)040	66.0	10	40	2.16	105	
25 V _{DC} AT +105 °C; 16.8 V _{DC} AT +125 °C								
15	B	T56B156M025C(1)(2)100	37.5	8	100	1.14	105	
15	V	T56V156M025C(1)(2)125	37.5	10	125	1.22	105	
22	V	T56V226M025C(1)(2)040	55.0	10	40	2.16	105	
33	D	T56D336M025C(1)(2)060	82.5	10	60	1.93	125	•
33	V	T56V336M025C(1)(2)040	82.5	10	40	2.16	105	
100	D	T56D107M025C(1)(2)060	250.0	10	60	1.93	105	
35 V _{DC} AT +105 °C; 23.5 V _{DC} AT +125 °C								
10	B	T56B106M035C(1)(2)200	35.0	8	200	0.80	105	
10	D	T56D106M035C(1)(2)120	35.0	10	120	1.36	125	•
15	V	T56V156M035C(1)(2)125	52.5	10	125	1.22	105	
22	D	T56D226M035C(1)(2)120	77.0	10	120	1.36	105	
50 V _{DC} AT +105 °C; 33.5 V _{DC} AT +125 °C								
10	D	T56D106M050C(1)(2)120	50.0	10	120	1.36	105	

Note

- Part number definitions:
 - (1) Reliability level: Z, S
 - (2) Surge current: A, B, S

RECOMMENDED VOLTAGE DERATING GUIDELINES

CAPACITOR VOLTAGE RATING AT -55 °C TO +105 °C	CAPACITOR CATEGORY VOLTAGE AT +105 °C TO +125 °C	RECOMMENDED VOLTAGE DERATING AT -55 °C TO +105 °C	RECOMMENDED VOLTAGE DERATING AT +105 °C TO +125 °C
2.5	1.7	2.3	1.5
4	2.7	3.6	2.4
6.3	4.2	5.7	3.8
10	6.7	9	6.0
16	10.7	12.8	8.6
20	13.4	16	10.8
25	16.8	20	13.5
35	23.5	28	18.9
50	33.5	40	27.0

RECOMMENDED TEMPERATURE DERATING

POWER DISSIPATION

CASE CODE	MAXIMUM PERMISSIBLE POWER DISSIPATION (W) AT $\leq +45$ °C IN FREE AIR
D	0.225

STANDARD PACKAGING QUANTITY

CASE CODE	UNITS PER 7" REEL
D	500

PERFORMANCE CHARACTERISTICS			
ITEM	CONDITION	POST TEST PERFORMANCE	
Life test	2000 h application of rated voltage at 105 °C ⁽¹⁾ , 2000 h application of 2/3 rated voltage at 125 °C ⁽¹⁾ , MIL-STD-202 method 108	Capacitance change	Within ± 20 % of initial value
		Dissipation factor	Within initial limits
		Leakage current	Shall not exceed 300 % of initial limit
Shelf life test	2000 h no voltage applied at 105 °C ⁽¹⁾ , 2000 h no voltage applied at 125 °C ⁽¹⁾ , MIL-STD-202 method 108	Capacitance change	Within ± 20 % of initial value
		Dissipation factor	Within initial limits
		Leakage current	Shall not exceed 300 % of initial limit
Humidity tests	At 60 °C / 90 % RH 500 h, no voltage applied ⁽¹⁾ At 85 °C / 85 % RH 500 h, rated voltage applied ⁽¹⁾	Capacitance change	-5 % to +50 % of initial value
		Dissipation factor	Within initial limit
		Leakage current	Shall not exceed 300 % of initial limit
Resistance to solder heat	MIL-STD-202, method 210, condition J (SnPb capacitors) and K (Pb-free capacitors)	Capacitance change	Within ± 20 % of initial value
		Dissipation factor	Within initial limit
		Leakage current	Shall not exceed 300 % of initial limit
Stability at low and high temperatures	-55 °C	Capacitance change	Within -30 % to 0 % of initial value
		Dissipation factor	Shall not exceed 150 % of initial limit
		Leakage current	n/a
	25 °C	Capacitance change	Within ± 20 % of initial value
		Dissipation factor	Within initial limit
		Leakage current	Within initial limit
	85 °C	Capacitance change	Within -50 % to +30 % of initial value
		Dissipation factor	Within initial limit
		Leakage current	Shall not exceed 1000 % of initial value
	105 °C / 125 °C ⁽¹⁾	Capacitance change	Within 0 % to +50 % of initial value
		Dissipation factor	Within initial limit
		Leakage current	Shall not exceed 1000 % of initial limit
Surge voltage	105 °C, 1000 successive test cycles at 1.3 of rated voltage in series with a 33 Ω resistor at the rate of 30 s ON, 30 s OFF	Capacitance change	Within ± 20 % of initial value
		Dissipation factor	Within initial limit
		Leakage current	Shall not exceed 300 % of initial limit
Shock (specified pulse)	MIL-STD-202, method 213, condition I, 100 g peak	Capacitance change	Within ± 20 % of initial value
		Dissipation factor	Within initial limit
		Leakage current	Shall not exceed 300 % of initial limit
		There shall be no mechanical or visual damage to capacitors post-conditioning.	
Vibration	MIL-STD-202, method 204, condition D, 10 Hz to 2000 Hz 20 g peak	Capacitance change	Within ± 20 % of initial value
		Dissipation factor	Within initial limit
		Leakage current	Shall not exceed 300 % of initial limit
		There shall be no mechanical or visual damage to capacitors post-conditioning.	
Shear test	Apply a pressure load of 5 N for 10 s ± 1 s horizontally to the center of capacitor side body	Capacitance change	Within ± 20 % of initial value
		Dissipation factor	Within initial limit
		Leakage current	Shall not exceed 300 % of initial limit

Note
⁽¹⁾ Test temperature and test conditions, please refer to table “Standard Ratings”

PRODUCT INFORMATION	
Polymer Guide	www.vishay.com/doc?40076
Moisture Sensitivity	www.vishay.com/doc?40135
Infographic	www.vishay.com/doc?48084
Sample Board	www.vishay.com/doc?48073
FAQ	
Frequently Asked Questions	www.vishay.com/doc?42106



Guide for Tantalum Solid Electrolyte Chip Capacitors With Polymer Cathode

INTRODUCTION

Tantalum electrolytic capacitors are the preferred choice in applications where volumetric efficiency, stable electrical parameters, high reliability, and long service life are primary considerations. The stability and resistance to elevated temperatures of the tantalum/tantalum oxide/manganese dioxide system make solid tantalum capacitors an appropriate choice for today's surface mount assembly technology.

Vishay Sprague has been a pioneer and leader in this field, producing a large variety of tantalum capacitor types for consumer, industrial, automotive, military, and aerospace electronic applications.

Tantalum is not found in its pure state. Rather, it is commonly found in a number of oxide minerals, often in combination with Columbium ore. This combination is known as "tantalite" when its contents are more than one-half tantalum. Important sources of tantalite include Australia, Brazil, Canada, China, and several African countries. Synthetic tantalite concentrates produced from tin slags in Thailand, Malaysia, and Brazil are also a significant raw material for tantalum production.

Electronic applications, and particularly capacitors, consume the largest share of world tantalum production. Other important applications for tantalum include cutting tools (tantalum carbide), high temperature super alloys, chemical processing equipment, medical implants, and military ordnance.

Vishay Sprague is a major user of tantalum materials in the form of powder and wire for capacitor elements and rod and sheet for high temperature vacuum processing.

THE BASICS OF TANTALUM CAPACITORS

Most metals form crystalline oxides which are non-protecting, such as rust on iron or black oxide on copper. A few metals form dense, stable, tightly adhering, electrically insulating oxides. These are the so-called "valve" metals and include titanium, zirconium, niobium, tantalum, hafnium, and aluminum. Only a few of these permit the accurate control of oxide thickness by electrochemical means. Of these, the most valuable for the electronics industry are aluminum and tantalum.

Capacitors are basic to all kinds of electrical equipment, from radios and television sets to missile controls and automobile ignitions. Their function is to store an electrical charge for later use.

Capacitors consist of two conducting surfaces, usually metal plates, whose function is to conduct electricity. They are separated by an insulating material or dielectric. The dielectric used in all tantalum electrolytic capacitors is tantalum pentoxide.

Tantalum pentoxide compound possesses high-dielectric strength and a high-dielectric constant. As capacitors are being manufactured, a film of tantalum pentoxide is applied to their electrodes by means of an electrolytic process. The film is applied in various thicknesses and at various voltages and although transparent to begin with, it takes on different colors as light refracts through it. This coloring occurs on the tantalum electrodes of all types of tantalum capacitors.

Rating for rating, tantalum capacitors tend to have as much as three times better capacitance/volume efficiency than aluminum electrolytic capacitors. An approximation of the capacitance/volume efficiency of other types of capacitors may be inferred from the following table, which shows the dielectric constant ranges of the various materials used in each type. Note that tantalum pentoxide has a dielectric constant of 26, some three times greater than that of aluminum oxide. This, in addition to the fact that extremely thin films can be deposited during the electrolytic process mentioned earlier, makes the tantalum capacitor extremely efficient with respect to the number of microfarads available per unit volume. The capacitance of any capacitor is determined by the surface area of the two conducting plates, the distance between the plates, and the dielectric constant of the insulating material between the plates.

COMPARISON OF CAPACITOR DIELECTRIC CONSTANTS

DIELECTRIC	ϵ DIELECTRIC CONSTANT
Air or vacuum	1.0
Paper	2.0 to 6.0
Plastic	2.1 to 6.0
Mineral oil	2.2 to 2.3
Silicone oil	2.7 to 2.8
Quartz	3.8 to 4.4
Glass	4.8 to 8.0
Porcelain	5.1 to 5.9
Mica	5.4 to 8.7
Aluminum oxide	8.4
Tantalum pentoxide	26
Ceramic	12 to 400K

In the tantalum electrolytic capacitor, the distance between the plates is very small since it is only the thickness of the tantalum pentoxide film. As the dielectric constant of the tantalum pentoxide is high, the capacitance of a tantalum capacitor is high if the area of the plates is large:

$$C = \frac{\epsilon A}{t}$$

where

C = capacitance

ϵ = dielectric constant

A = surface area of the dielectric

t = thickness of the dielectric

Tantalum capacitors contain either liquid or solid electrolytes. In solid electrolyte capacitors, a dry material (manganese dioxide) forms the cathode plate. A tantalum lead is embedded in or welded to the pellet, which is in turn connected to a termination or lead wire. The drawings show the construction details of the surface mount types of tantalum capacitors shown in this catalog.

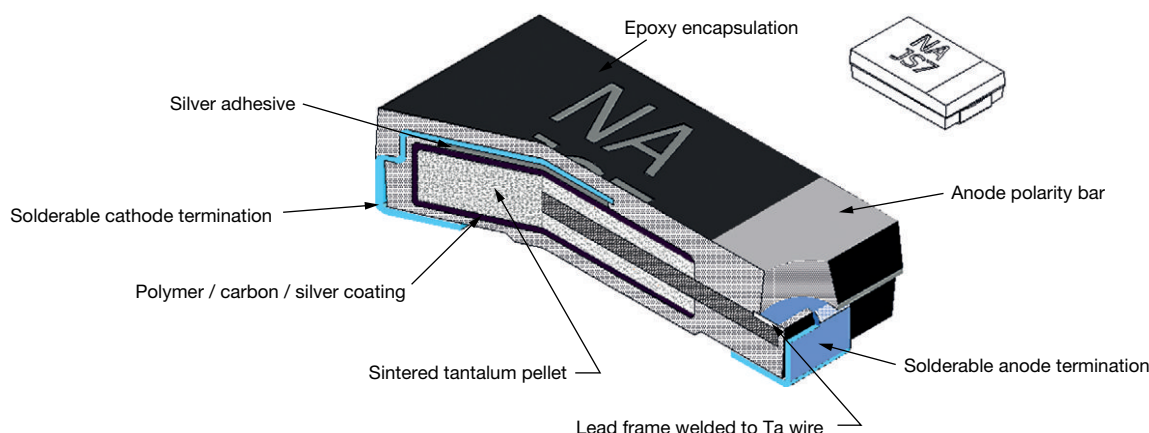
SOLID ELECTROLYTE POLYMER TANTALUM CAPACITORS

Solid electrolyte polymer capacitors utilize sintered tantalum pellets as anodes. Tantalum pentoxide dielectric layer is formed on the entire surface of anode, which is further impregnated with highly conductive polymer as cathode system.

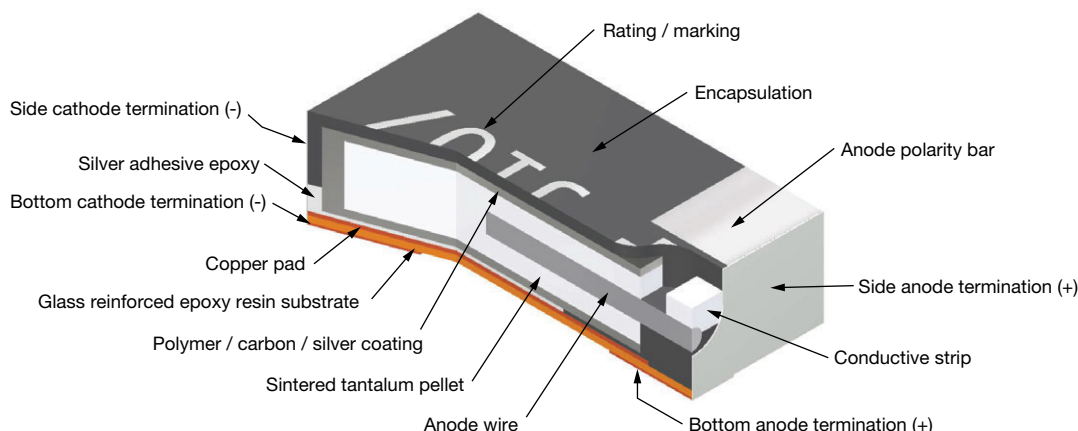
The conductive polymer layer is then coated with graphite, followed by a layer of metallic silver, which provides a conductive surface between the capacitor element and the outer termination (lead frame or other).

Molded chip polymer tantalum capacitor encases the element in plastic resins, such as epoxy materials. The molding compound has been selected to meet the requirements of UL 94 V-0 and outgassing requirements of ASTM E-595. After assembly, the capacitors are tested and inspected to assure long life and reliability. It offers excellent reliability and high stability for variety of applications in electronic devices. Usage of conductive polymer cathode system provides very low equivalent series resistance (ESR), which makes the capacitors particularly suitable for high frequency applications.

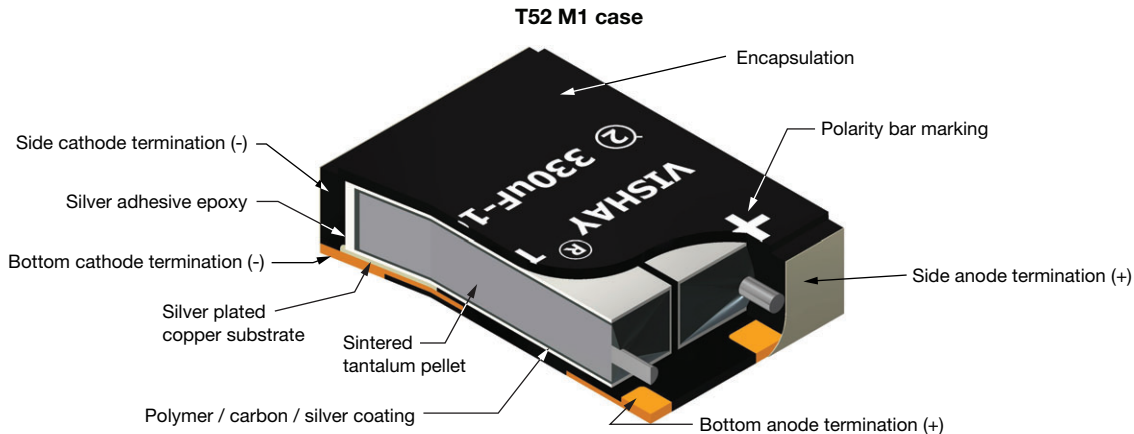
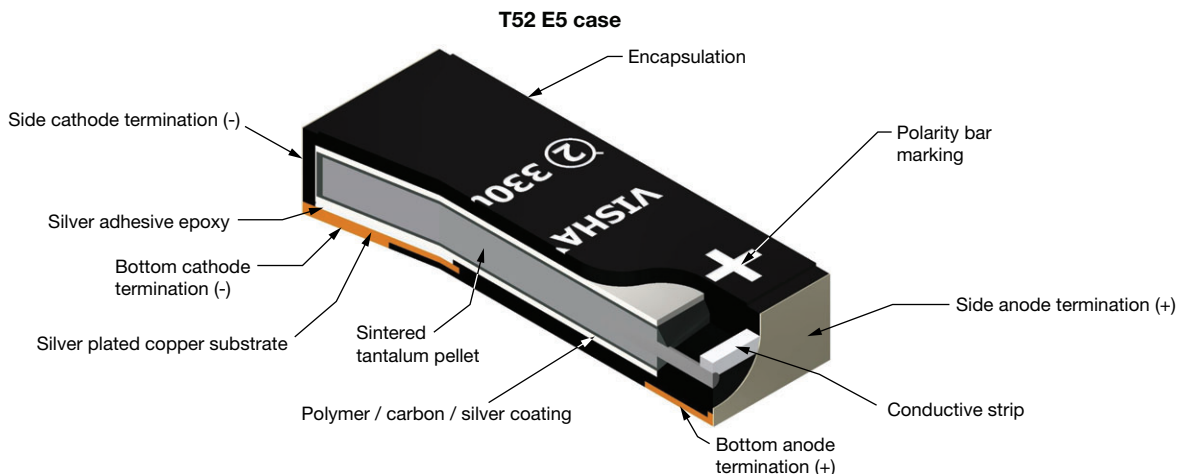
TANTALUM CAPACITOR WITH POLYMER CATHODE TYPE T50 / T51 / T55 / T56



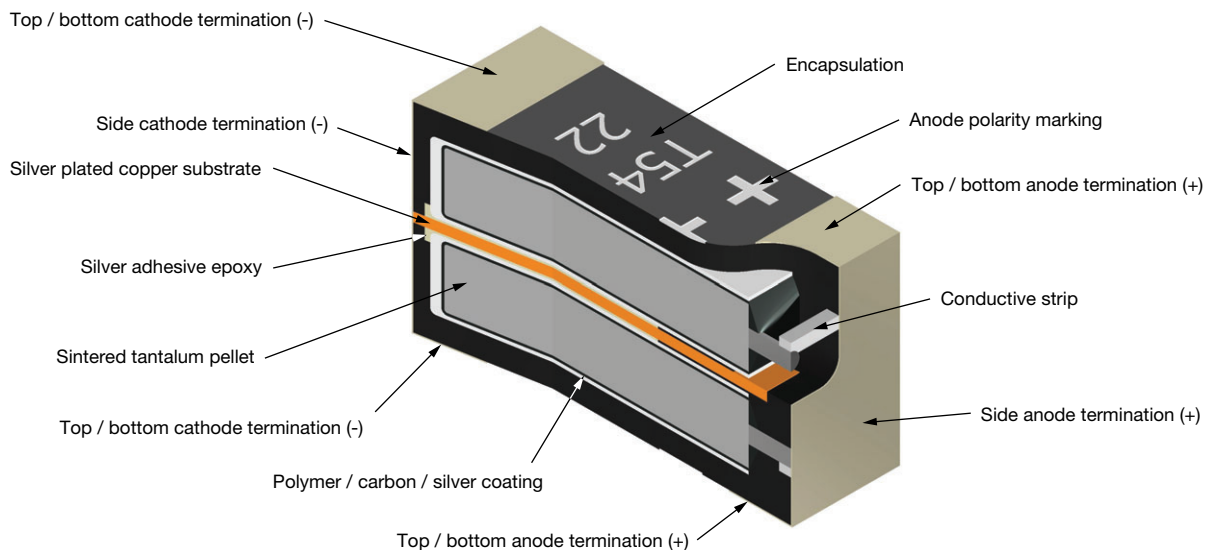
TANTALUM CAPACITOR WITH POLYMER CATHODE TYPE T58



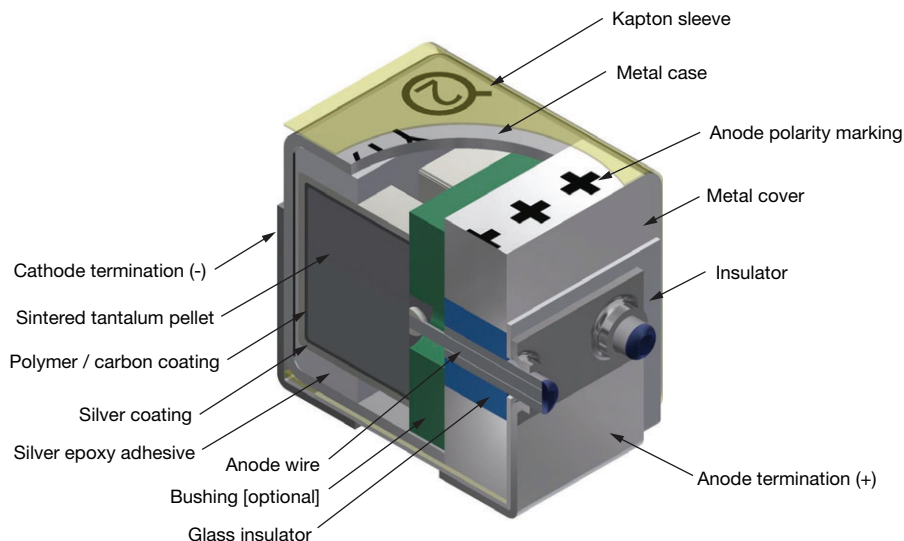
TANTALUM CAPACITOR WITH POLYMER CATHODE TYPE T52



TANTALUM CAPACITOR WITH POLYMER CATHODE TYPE T54 / T59 / 20021

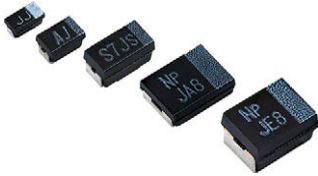


HERMETICALLY SEALED TANTALUM CAPACITOR WITH POLYMER CATHODE TYPE T27



POLYMER CAPACITORS - METAL CASE, HERMETICALLY SEALED

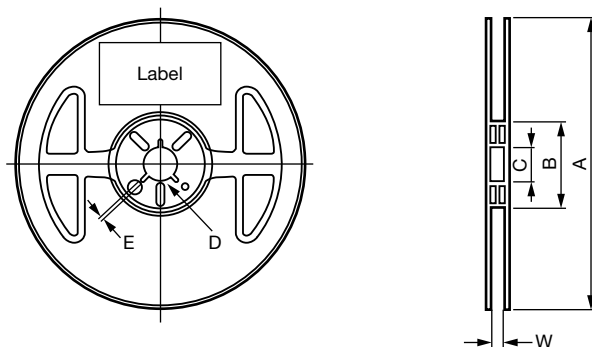
SERIES	T27
PRODUCT IMAGE	
TYPE	VPolyTan™ hermetically sealed polymer surface-mount chip capacitors, low ESR
FEATURES	Hermetically sealed in metal case, low ESR / low DCL, hi-rel. processing
TEMPERATURE RANGE	-55 °C to +125 °C
CAPACITANCE RANGE	15 µF to 470 µF
VOLTAGE RANGE	16 V to 75 V
CAPACITANCE TOLERANCE	± 20 %
LEAKAGE CURRENT	0.05 CV
DISSIPATION FACTOR	12 %
ESR	25 mΩ to 100 mΩ
CASE SIZES	D
TERMINATION FINISH	100 % tin; tin / lead

POLYMER CAPACITORS - MOLDED CASE	
SERIES	T50, T51, T55, T56
PRODUCT IMAGE	
TYPE	VPolyTan™, molded case, high performance polymer
FEATURES	High performance
TEMPERATURE RANGE	-55 °C to +105 °C / +125 °C
CAPACITANCE RANGE	3.3 µF to 1000 µF
VOLTAGE RANGE	2.5 V to 63 V
CAPACITANCE TOLERANCE	± 20 %
LEAKAGE CURRENT	0.1 CV
DISSIPATION FACTOR	8 % to 10 %
ESR	6 mΩ to 500 mΩ
CASE SIZES	J, P, A, T, B, Z, V, D, C
TERMINATION FINISH	Cases J, P, C: 100 % tin Case A, T, B, Z, V, D: Ni / Pd / Au

POLYMER CAPACITORS - LEADFRAMELESS MOLDED CASE					
SERIES	T52	T58	T59	T54	20021
PRODUCT IMAGE					
TYPE	vPolyTan™ polymer surface mount chip capacitors, low profile, leadframeless molded type	vPolyTan™ polymer surface mount chip capacitors, compact, leadframeless molded type	vPolyTan™ polymer surface mount chip capacitors, low ESR, leadframeless molded type	vPolyTan™ polymer surface mount chip capacitors, low ESR, leadframeless molded type, hi-rel commercial off-the-shelf (COTS)	vPolyTan™ polymer surface mount chip capacitors, low ESR, leadframeless molded type, DLA approved
FEATURES	Low profile	Small case size	Multinode	Hi-rel COTS, multinode	Multinode
TEMPERATURE RANGE	-55 °C to +105 °C	-55 °C to +105 °C	-55 °C to +105 °C	-55 °C to +125 °C	-55 °C to +125 °C
CAPACITANCE RANGE	47 µF to 1500 µF	1 µF to 330 µF	15 µF to 470 µF	15 µF to 470 µF (discrete capacitors) 30 µF to 2800 µF (stacked capacitors)	15 µF to 470 µF
VOLTAGE RANGE	10 V to 35 V	6.3 V to 35 V	16 V to 75 V	16 V to 75 V	16 V to 63 V
CAPACITANCE TOLERANCE	± 20 %	± 20 %	± 10 %, ± 20 %	± 20 %	± 20 %
LEAKAGE CURRENT	0.1 CV				
DISSIPATION FACTOR	10 %	8 % to 14 %	12 %	12 %	10 %
ESR	25 mΩ to 55 mΩ	50 mΩ to 500 mΩ	25 mΩ to 150 mΩ	5 mΩ to 150 mΩ	25 mΩ to 150 mΩ
CASE SIZES	E5, M1, M9, B2	MM, W0, W9, A0, BB	EE	EE, E2, E3, E4, E6	EE
TERMINATION	100 % tin		100 % tin; tin / lead		Tin / lead

MOLDED CAPACITORS, T50 / T51 / T55 / T56 TYPES

PLASTIC TAPE AND REEL PACKAGING DIMENSIONS in millimeters

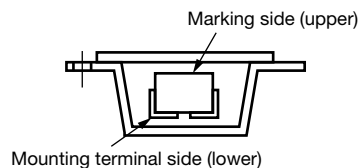
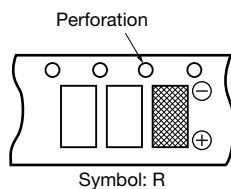
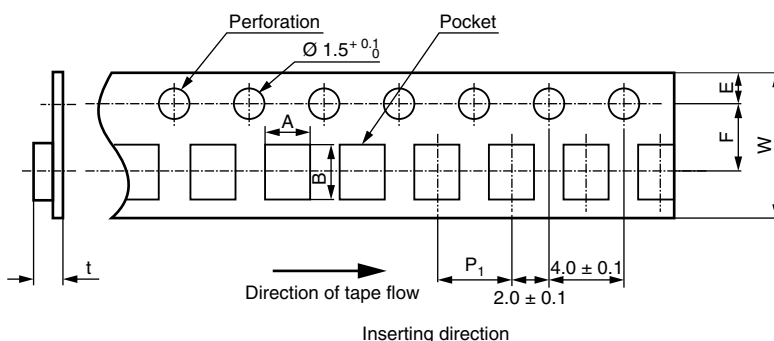


TAPE WIDTH	8	12
A + 0 / - 3		Ø 180
B + 1 / 0		Ø 60
C ± 0.2		Ø 13
D ± 0.5		Ø 21
E ± 0.5		2.0
W ± 0.3	9.0	13.0

Note

- A reel diameter of 330 mm is also applicable

PLASTIC TAPE SIZE DIMENSIONS in millimeters



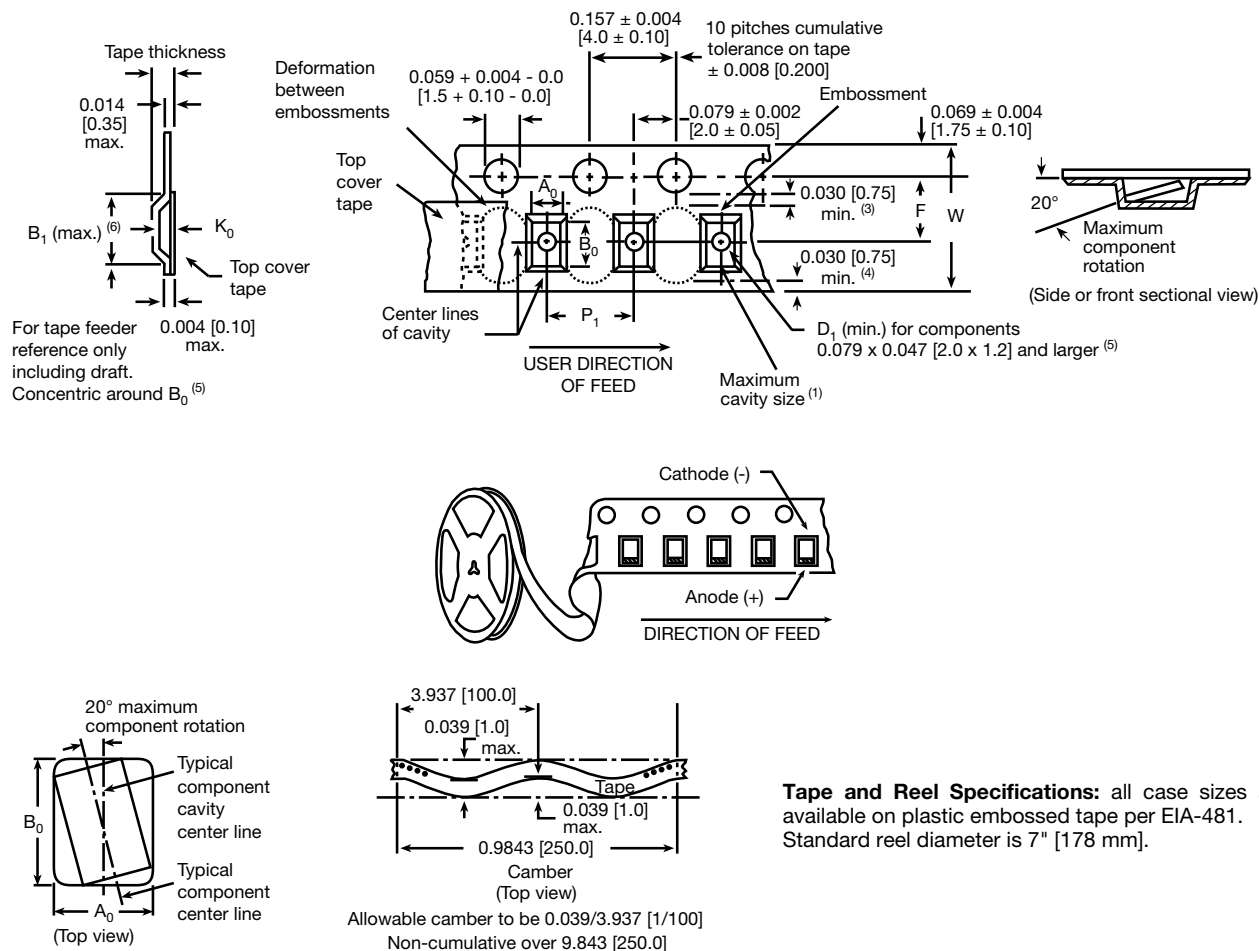
CASE CODE	A ± 0.2	B ± 0.2	W ± 0.3	F ± 0.1	E ± 0.1	P ₁ ± 0.1	t _{max.}
J	1.0	1.8	8.0	3.5	1.75	4.0	1.3
P	1.4	2.2	8.0	3.5	1.75	4.0	1.6
A	1.9	3.5	8.0	3.5	1.75	4.0	2.5
T	3.1	3.8	8.0	3.5	1.75	4.0	1.7
B	3.1	3.8	8.0	3.5	1.75	4.0	2.5
C	3.7	6.3	12.0	5.5	1.75	8.0	3.1
Z	4.8	7.7	12.0	5.5	1.75	8.0	2.6
V	4.8	7.7	12.0	5.5	1.75	8.0	2.6
D	4.8	7.7	12.0	5.5	1.75	8.0	3.4

Note

- A reel diameter of 330 mm is also applicable

LEADFRAMELESS MOLDED CAPACITORS, ALL TYPES

PLASTIC TAPE AND REEL PACKAGING in inches [millimeters]



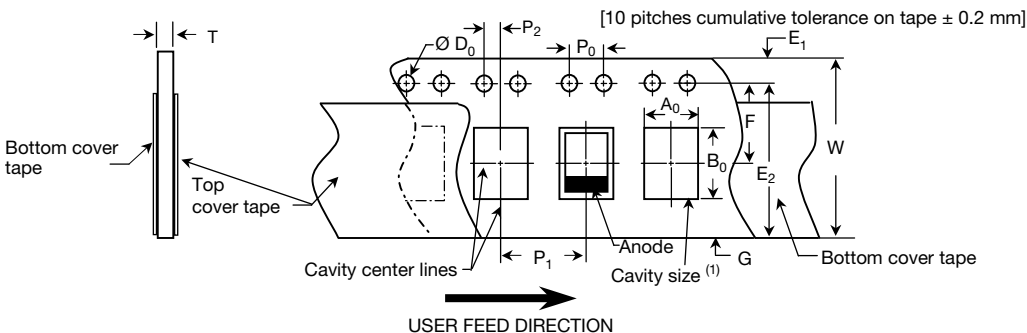
Notes

- Metric dimensions will govern. Dimensions in inches are rounded and for reference only
- A_0 , B_0 , K_0 , are determined by the maximum dimensions to the ends of the terminals extending from the component body and / or the body dimensions of the component. The clearance between the ends of the terminals or body of the component to the sides and depth of the cavity (A_0 , B_0 , K_0) must be within 0.002" (0.05 mm) minimum and 0.020" (0.50 mm) maximum. The clearance allowed must also prevent rotation of the component within the cavity of not more than 20°
- Tape with components shall pass around radius "R" without damage. The minimum trailer length may require additional length to provide "R" minimum for 12 mm embossed tape for reels with hub diameters approaching N minimum
- This dimension is the flat area from the edge of the sprocket hole to either outward deformation of the carrier tape between the embossed cavities or to the edge of the cavity whichever is less
- This dimension is the flat area from the edge of the carrier tape opposite the sprocket holes to either the outward deformation of the carrier tape between the embossed cavity or to the edge of the cavity whichever is less
- The embossed hole location shall be measured from the sprocket hole controlling the location of the embossment. Dimensions of embossment location shall be applied independent of each other
- B_1 dimension is a reference dimension tape feeder clearance only

CARRIER TAPE DIMENSIONS in inches [millimeters]								
CASE CODE	TAPE SIZE	B ₁ (MAX.) ⁽¹⁾	D ₁ (MIN.)	F	K ₀ (MAX.)	P ₁	P ₂	W
E5	12 mm	0.329 [8.35]	0.059 [1.5]	0.217 ± 0.002 [5.50 ± 0.05]	0.071 [1.8]	0.315 ± 0.004 [8.0 ± 0.10]	0.079 ± 0.002 [2.00 ± 0.05]	0.476 ± 0.008 [12.1 ± 0.20]
MM ⁽²⁾	8 mm	0.075 [1.91]	0.02 [0.5]	0.138 [3.5]	0.043 [1.10]	0.157 [4.0]	0.079 ± 0.002 [2.00 ± 0.05]	0.315 [8.0]
M1, M9	12 mm	0.32 [8.2]	0.059 [1.5]	0.217 ± 0.002 [5.5 ± 0.05]	0.094 [2.39]	0.315 ± 0.04 [8.0 ± 1.0]	0.079 ± 0.002 [2.00 ± 0.05]	0.472 + 0.012 / - 0.004 [12.0 + 0.3 / - 0.10]
W9	8 mm	0.126 [3.20]	0.030 [0.75]	0.138 [3.5]	0.045 [1.15]	0.157 [4.0]	0.079 ± 0.002 [2.00 ± 0.05]	0.315 [8.0]
W0	8 mm	0.126 [3.20]	0.030 [0.75]	0.138 [3.5]	0.045 [1.15]	0.157 [4.0]	0.079 ± 0.002 [2.00 ± 0.05]	0.315 [8.0]
A0	8 mm	-	0.02 [0.5]	0.138 [3.5]	0.049 [1.25]	0.157 [4.0]	0.079 ± 0.002 [2.00 ± 0.05]	0.315 [8.0]
BB	8 mm	0.157 [4.0]	0.039 [1.0]	0.138 [3.5]	0.087 [2.22]	0.157 [4.0]	0.079 ± 0.002 [2.00 ± 0.05]	0.315 [8.0]
EE	12 mm	0.32 [8.2]	0.059 [1.5]	0.217 ± 0.002 [5.5 ± 0.05]	0.175 [4.44]	0.315 ± 0.04 [8.0 ± 1.0]	0.079 ± 0.002 [2.00 ± 0.05]	0.472 + 0.012 / - 0.004 [12.0 + 0.3 / - 0.10]
B2	8 mm	0.157 [4.0]	0.039 [1.0]	0.138 [3.5]	0.057 [1.45]	0.157 [4.0]	0.079 ± 0.002 [2.00 ± 0.05]	0.315 [8.0]
D ⁽³⁾	16 mm	0.321 [8.16]	0.059 [1.5]	0.295 ± 0.004 [7.50 ± 0.1]	0.308 [7.83]	0.472 ± 0.004 [12.00 ± 0.1]	0.079 ± 0.004 [2.00 ± 0.1]	0.630 ± 0.012 [16.00 ± 0.3]

Notes

- (1) For reference only
(2) Standard packaging of MM case is with paper tape. Plastic tape is available per request
(3) Tape thickness 0.018 [0.45] max.

PAPER TAPE AND REEL PACKAGING DIMENSIONS in inches [millimeters]											
											
CASE SIZE	TAPE SIZE	A ₀	B ₀	D ₀	P ₀	P ₁	P ₂	E	F	W	T
MM	8 mm	0.041 ± 0.002 [1.05 ± 0.05]	0.071 ± 0.002 [1.8 ± 0.05]	0.06 ± 0.004 [1.5 ± 0.1]	0.157 ± 0.004 [4.0 ± 0.1]	0.157 ± 0.004 [4.0 ± 0.1]	0.079 ± 0.002 [2.0 ± 0.05]	0.069 ± 0.004 [1.75 ± 0.1]	0.0138 ± 0.002 [3.5 ± 0.05]	0.315 ± 0.008 [8.0 ± 0.2]	0.037 ± 0.002 [0.95 ± 0.05]
M0	8 mm	0.049 ± 0.002 [1.25 ± 0.05]	0.081 ± 0.002 [2.05 ± 0.05]	0.06 ± 0.004 [1.5 ± 0.1]	0.157 ± 0.004 [4.0 ± 0.1]	0.157 ± 0.004 [4.0 ± 0.1]	0.079 ± 0.002 [2.0 ± 0.05]	0.069 ± 0.004 [1.75 ± 0.1]	0.0138 ± 0.002 [3.5 ± 0.05]	0.315 ± 0.008 [8.0 ± 0.2]	0.041 ± 0.002 [1.05 ± 0.05]

Note

- (1) A₀, B₀ are determined by the maximum dimensions to the ends of the terminals extending from the component body and / or the body dimensions of the component. The clearance between the ends of the terminals or body of the component to the sides and depth of the cavity (A₀, B₀) must be within 0.002" (0.05 mm) minimum and 0.020" (0.50 mm) maximum. The clearance allowed must also prevent rotation of the component within the cavity of not more than 20°

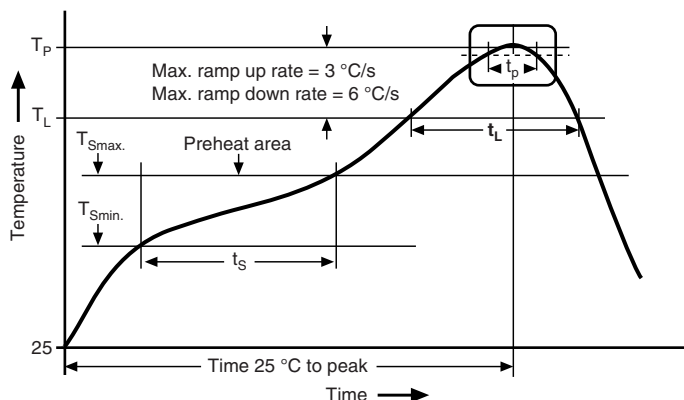
**PACKING AND STORAGE**

Polymer capacitors meet moisture sensitivity level rating (MSL) of 3 or 4 as specified in IPC/JEDEC® J-STD-020 and are dry packaged in moisture barrier bags (MBB) per J-STD-033. MSL for each particular family is defined in the datasheet - either in "Features" section or "Standard Ratings" table. Level 3 specifies a floor life (out of bag) of 168 hours and level 4 specifies a floor life of 72 hours at 30 °C maximum and 60 % relative humidity (RH). Unused capacitors should be re-sealed in the MBB with fresh desiccant. A moisture strip (humidity indicator card) is included in the bag to assure dryness. To remove excess moisture, capacitors can be dried at 40 °C (standard "dry box" conditions).

For detailed recommendations please refer to J-STD-033.

RECOMMENDED REFLOW PROFILES

Vishay recommends no more than 3 cycles of reflow in accordance with J-STD-020.



PROFILE FEATURE	SnPb EUTECTIC ASSEMBLY	LEAD (Pb)-FREE ASSEMBLY
PREHEAT AND SOAK		
Temperature min. ($T_{Smin.}$)	100 °C	150 °C
Temperature max. ($T_{Smax.}$)	150 °C	200 °C
Time (t_s) from ($T_{Smin.}$ to $T_{Smax.}$)	60 s to 120 s	60 s to 120 s
RAMP UP		
Ramp-up rate (T_L to T_P)	3 °C/s maximum	
Liquidus temperature (T_L)	183 °C	217 °C
Time (t_L) maintained above T_L	60 s to 150 s	
Peak package body temperature (T_P) max.	Depends on type and case - see table below	
Time (t_p) within 5 °C of the peak max. temperature	20 s	5 s ⁽¹⁾
RAMP DOWN		
Ramp-down rate (T_P to T_L)	6 °C/s maximum	
Time from 25 °C to peak temperature	6 min maximum	8 min maximum

Note

⁽¹⁾ For T27, lead (Pb)-free capacitors $t_p = 30$ s

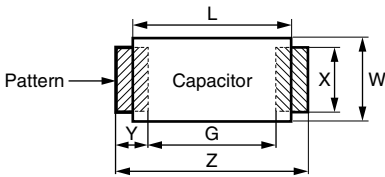
PEAK PACKAGE BODY TEMPERATURE (T_P) MAXIMUM

TYPE	CASE CODE	PEAK PACKAGE BODY TEMPERATURE (T_P) MAX.	
		SnPb EUTECTIC ASSEMBLY	LEAD (Pb)-FREE ASSEMBLY
T27	D	220 °C	245 °C
T55	J, P, A, T, B, C, Z, V, D	n/a	260 °C
T52	E5, M1, M9, B2		260 °C
T58	MM, W9, W0, A0, BB		260 °C
T50	D		260 °C
T51	D, V		260 °C
T56	B, D, V		250 °C
T59	EE	220 °C	250 °C
T54	3E, 6E, EE, E2, E3, E4, E6	220 °C	250 °C
20021	EE	220 °C	n/a

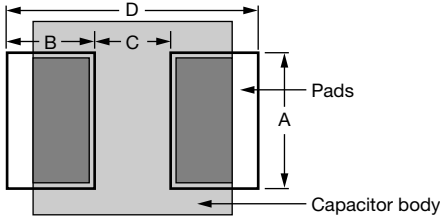
Notes

- T50, T51, T52, T55, T56, and T58 capacitors are process sensitive.
PSL classification to JEDEC J-STD-075: R4G
- T54 and T59 capacitors with 100 % tin termination are process sensitive.
PSL classification to JEDEC J-STD-075: R6G

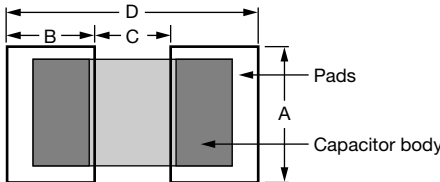
MOLDED CAPACITORS, T50 / T51 / T55 / T56 TYPES

PAD DIMENSIONS in millimeters						
						
CASE / DIMENSIONS	CAPACITOR SIZE		PAD DIMENSIONS			
	L	W	G (max.)	Z (min.)	X (min.)	Y (Ref.)
J	1.6	0.8	0.7	2.5	1.0	0.9
P	2.0	1.25	0.5	2.6	1.2	1.05
A	3.2	1.6	1.1	3.8	1.5	1.35
T / B	3.5	2.8	1.4	4.1	2.7	1.35
C	5.8	3.2	2.9	6.9	2.7	2.0
Z / V / D	7.3	4.3	4.1	8.2	2.9	2.05

LEADFRAMELESS MOLDED CAPACITORS T52 / T58

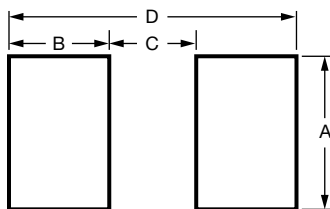
PAD DIMENSIONS in inches [millimeters]					
					
FAMILY	CASE CODE	A (NOM.)	B (MIN.)	C (NOM.)	D (MIN.)
T52	E5	0.094 [2.40]	0.077 [1.95]	0.180 [4.57]	0.333 [8.46]
	M1, M9	0.178 [4.52]	0.098 [2.48]	0.138 [3.50]	0.333 [8.46]
	B2	0.081 [2.06]	0.057 [1.44]	0.070 [1.77]	0.183 [4.64]
T58	MM	0.024 [0.61]	0.027 [0.70]	0.025 [0.64]	0.080 [2.03]
	W0, W9	0.035 [0.89]	0.029 [0.74]	0.041 [1.05]	0.099 [2.52]
	A0	0.047 [1.19]	0.042 [1.06]	0.065 [1.65]	0.148 [3.76]
	BB	0.094 [2.39]	0.044 [1.11]	0.072 [1.82]	0.159 [4.03]

LEADFRAMELESS MOLDED CAPACITORS T59 / T54 / 20021

PAD DIMENSIONS in inches [millimeters]					
					
FAMILY	CASE CODE	A (NOM.)	B (MIN.)	C (NOM.)	D (MIN.)
T59 / T54	EE	0.209 [5.30]	0.098 [2.50]	0.169 [4.30]	0.366 [9.30]
T54	E2 / E3	0.128 [3.24]	0.120 [3.04]	0.154 [3.92]	0.394 [10.0]
	E4 / E6	0.301 [7.64]	0.120 [3.04]	0.154 [3.92]	0.394 [10.0]
	3E	0.482 [12.24]	0.120 [3.04]	0.154 [3.92]	0.394 [10.0]
	6E	0.482 [12.24]	0.120 [3.04]	0.154 [3.92]	0.394 [10.0]
20021	EE	0.209 [5.30]	0.098 [2.50]	0.169 [4.30]	0.366 [9.30]

HERMETICALLY SEALED CAPACITOR T27 TYPE

PAD DIMENSIONS in inches [millimeters]



CASE CODE	A (MIN.)	B (NOM.)	C (NOM.)	D (NOM.)
D	0.295 [7.50]	0.138 [3.50]	0.100 [2.50]	0.374 [9.50]

GUIDE TO APPLICATION

- AC Ripple Current:** the maximum allowable ripple current shall be determined from the formula:

$$I_{RMS} = \sqrt{\frac{P}{R_{ESR}}}$$

where,

P = power dissipation in W at +45 °C as given in the tables in the product datasheets.

R_{ESR} = the capacitor equivalent series resistance at the specified frequency.

- AC Ripple Voltage:** the maximum allowable ripple voltage shall be determined from the formula:

$$V_{RMS} = Z \sqrt{\frac{P}{R_{ESR}}}$$

or, from the formula:

$$V_{RMS} = I_{RMS} \times Z$$

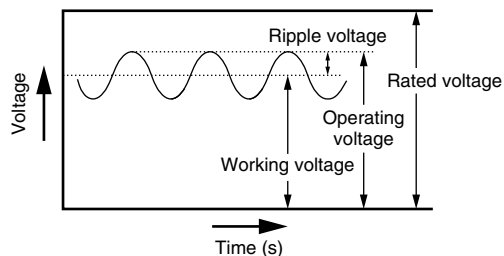
where,

P = power dissipation in W at +45 °C as given in the tables in the product datasheets.

R_{ESR} = The capacitor equivalent series resistance at the specified frequency.

Z = The capacitor impedance at the specified frequency.

- 2.1 The tantalum capacitors must be used in such a condition that the sum of the working voltage and ripple voltage peak values does not exceed the rated voltage as shown in figure below.



- Temperature Derating:** power dissipation is affected by the heat sinking capability of the mounting surface. If these capacitors are to be operated at temperatures above +45 °C, the permissible ripple current (or voltage) shall be calculated using the derating coefficient as shown in the table below:

MAXIMUM RIPPLE CURRENT TEMPERATURE DERATING FACTOR	
≤ 45 °C	1.0
55 °C	0.8
85 °C	0.6
105 °C	0.4
125 °C	0.25

- Reverse Voltage:** the capacitors are not intended for use with reverse voltage applied. However, they are capable of withstanding momentary reverse voltage peaks, which must not exceed the following values:
At 25 °C: 10 % of the rated voltage or 1 V, whichever is smaller.
At 85 °C: 5 % of the rated voltage or 0.5 V, whichever is smaller.
At 105 °C: 3 % of the rated voltage or 0.3 V, whichever is smaller.

- Mounting Precautions:**

- 5.1 **Soldering:** capacitors can be attached by conventional soldering techniques; vapor phase, convection reflow, infrared reflow, wave soldering, and hot plate methods. The soldering profile charts show recommended time / temperature conditions for soldering. Preheating is recommended. The recommended maximum ramp rate is 3 °C per second. Attachment with a soldering iron is not recommended due to the difficulty of controlling temperature and time at temperature. The soldering iron must never come in contact with the capacitor. For details see www.vishay.com/doc?40214.

- 5.2 **Limit Pressure on Capacitor Installation with Mouser:** pressure must not exceed 4.9 N with a tool end diameter of 1.5 mm when applied to the capacitors using an absorber, centering tweezers, or similar (maximum permitted pressurization time: 5 s). An excessively low absorber setting position would result in not only the application of undue force to the capacitors but capacitor and other component scattering, circuit board wiring breakage, and / or cracking as well, particularly when the capacitors are mounted together with other chips having a height of 1 mm or less.

5.3 **Flux Selection**

- 5.3.1 Select a flux that contains a minimum of chlorine and amine.

- 5.3.2 After flux use, the chlorine and amine in the flux remain must be removed.

- 5.4 **Cleaning After Mounting:** the following solvents are usable when cleaning the capacitors after mounting. Never use a highly active solvent.

- Halogen organic solvent (HCFC225, etc.)
- Alcoholic solvent (IPA, ethanol, etc.)
- Petroleum solvent, alkali saponifying agent, water, etc.

Circuit board cleaning must be conducted at a temperature of not higher than 50 °C and for an immersion time of not longer than 30 minutes. When an ultrasonic cleaning method is used, cleaning must be conducted at a frequency of 48 kHz or lower, at an vibrator output of 0.02 W/cm³, at a temperature of not higher than 40 °C, and for a time of 5 minutes or shorter.

Notes

- Care must be exercised in cleaning process so that the mounted capacitor will not come into contact with any cleaned object or the like or will not get rubbed by a stiff brush or similar. If such precautions are not taken particularly when the ultrasonic cleaning method is employed, terminal breakage may occur
- When performing ultrasonic cleaning under conditions other than stated above, conduct adequate advance checkout



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